Unit: mm

TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

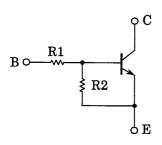
RN2301,RN2302,RN2303 RN2304,RN2305,RN2306

Switching, Inverter Circuit, Interface Circuit And Driver Circuit Applications

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1301~1306

Equivalent Circuit

Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN2301	4.7	4.7
RN2302	10	10
RN2303	22	22
RN2304	47	47
RN2305	2.2	47
RN2306	4.7	47

2.0±0.2 0.90±0.1 1.3±0.1 1.0±0.0 2.0±0.0 1.3±0.1 2.0±0.0 1.0±0.0 2.0±0.1 2.0±0.1 2.0±0.1 2.0±0.1 2.0±0.1 2.0±0.1 2.0±0.0 2.0±0.1 2.

BASE
 EMITTER
 COLLECTOR

_

JEDEC	_
EIAJ	SC-70
TOSHIBA	2-2E1A

Weight: 0.006g

Maximum Ratings (Ta = 25°C)

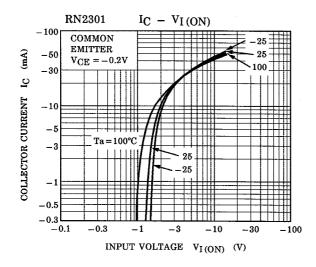
Characteristi	Symbol	Rating	Unit		
Collector-base voltage	RN2301~2306	V_{CBO}	-50	V	
Collector-emitter voltage	1(142301-2300	V _{CEO}	-50	٧	
Emitter-base voltage	RN2301~2304	V _{EBO}	-10	V	
	RN2305, 2306	vEBO.	-5		
Collector current		IC	-100	mA	
Collector power dissipation	RN2301~2306	PC	100	mW	
Junction temperature	KN2301~2300	Tj	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

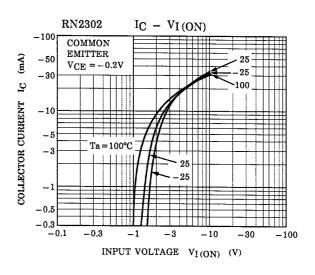


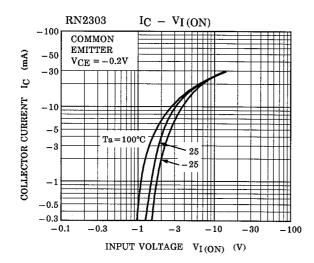
Electrical Characteristics (Ta = 25°C)

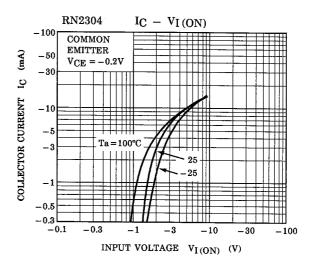
Characteris	stic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN2301~2306	I _{CBO}	_	V _{CB} = -50V, I _E = 0	_	_	-100	n ^
	KN2301~2300	I _{CEO}	_	V _{CE} = -50V, I _B = 0	_	_	-500	nA
Emitter cut-off current	RN2301	I _{EBO}	_	V _{EB} = −10V, I _C = 0	-0.82	_	-1.52	mA
	RN2302		_		-0.38	_	-0.71	
	RN2303		_		-0.17	_	-0.33	
	RN2304		_		-0.082	_	-0.15	
	RN2305		_	V _{EB} = -5V, I _C = 0	-0.078	_	-0.145	
	RN2306		_		-0.074	_	-0.138	
	RN2301		_		30	_	_	
	RN2302		_		50	_	_	
DO	RN2303	h _{FE}	_	- V _{CE} = −5V	70	_	_	_
DC current gain	RN2304		_	I _C = −10mA	80	_	_	
	RN2305		_		80	_	_	
	RN2306		_		80	_	_	
Collector-emitter saturation voltage	RN2301~2306	V _{CE (sat)}	_	$I_{C} = -5mA$ $I_{B} = -0.25mA$	_	-0.1	-0.3	V
	RN2301	VI (ON)	_	V _{CE} = -0.2V I _C = -5mA	-1.1	_	-2.0	- V
	RN2302		_		-1.2	_	-2.4	
	RN2303		_		-1.3	_	-3.0	
Input voltage (ON)	RN2304		_		-1.5	_	-5.0	
	RN2305		_		-0.6	_	-1.1	
	RN2306		_		-0.7	_	-1.3	
land valtage (OFF)	RN2301~2304	V _{I (OFF)}	_	V _{CE} = -5V, I _C = -0.1mA	-1.0	_	-1.5	V
Input voltage (OFF)	RN2305, 2306		_		-0.5	_	-0.8	
Translation frequency	RN2301~2306	f _T	_	V _{CE} = -10V, I _C = -5mA	_	200	_	MHz
Collector output capacitance	RN2301~2306	C _{ob}	_	V _{CB} = -10V, I _E = 0 f = 1MHz	_	3	6	pF
	RN2301	R1	_	7 10 15.4 22 32.9 47	3.29	4.7	6.11	· kΩ
	RN2302		_		7	10	13	
Input resistor	RN2303		_		15.4	22	28.6	
	RN2304		_		32.9	47	61.1	
	RN2305		_		2.2	2.86		
	RN2306		_		3.29	4.7	6.11	-
Resistor ratio	RN2301~2304	R1/R2	<u> </u>	0.9	1.0	1.1		
	RN2305		_		0.0421	0.0468	0.0515	_
	RN2306		_		0.09	0.1	0.11	

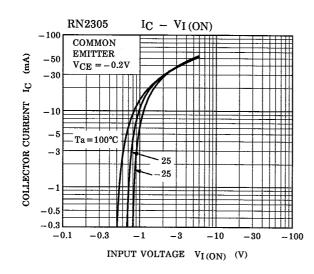
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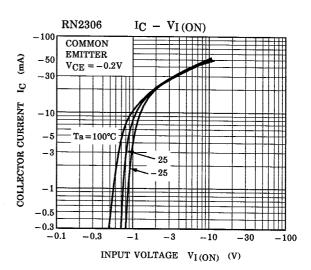


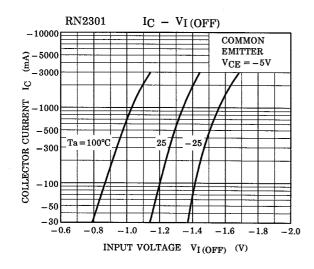


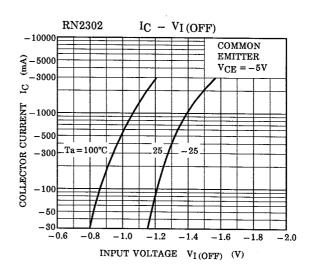


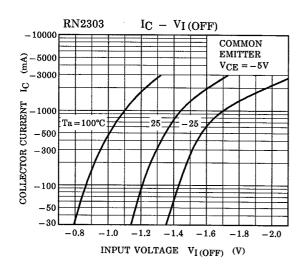


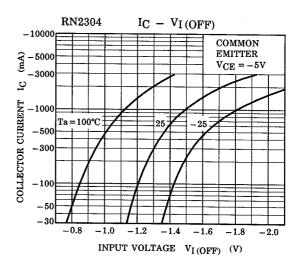


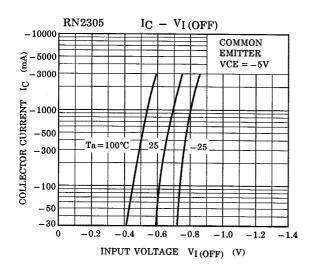


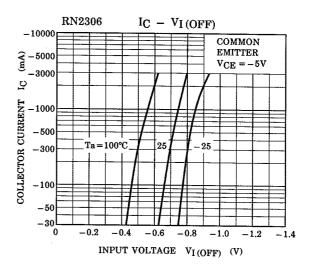


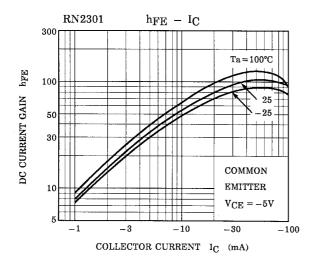


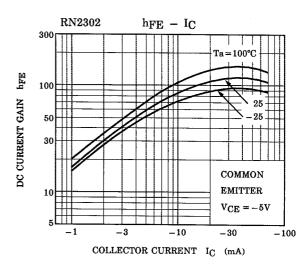


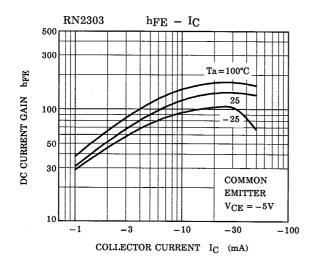


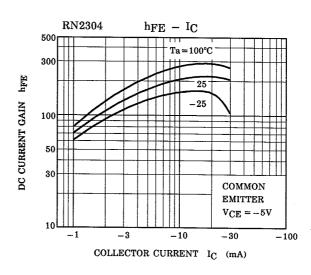


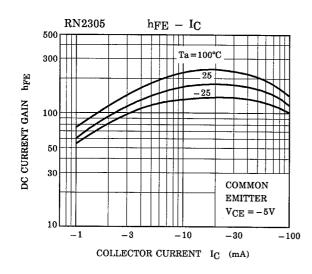


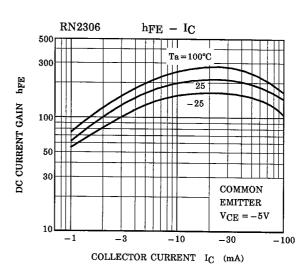












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Type Name	Marking
RN2301	Type Name YA
RN2302	Type Name Y B
RN2303	Type Name Y C
RN2304	Type Name Y D
RN2305	Type Name YE
RN2306	Type Name Y F

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